TOSHIBA CMOS DIGITAL INTEGRATED CIRCUIT SILICON MONOLITHIC

TC74LVX157F, TC74LVX157FN, TC74LVX157FT

QUAD 2-CHANNEL MULTIPLEXER

The TC74LVX157 is a high speed CMOS QUAD 2-CHANNEL MULTIPLEXER fabricated with silicon gate C²MOS technology.

Designed for use in 3.3 Volt systems, it achieves high speed operation while maintaining the CMOS low power dissipation. This device is suitable for low voltage and battery operated systems.

This device consist of four 2-input digital multiplexers with common select and strobe inputs.

When the STROBE input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs. An input protection circuit ensures that 0 to 7V can be applied to the input pins without regard to the supply voltage. This device can be used to interface 5V to 3V systems and two supply systems such as battery back up. This circuit prevents device destruction due to mismatched supply and input voltages.

FEATURES

• High speed : $t_{pd} = 5.1$ ns (Typ.) ($V_{CC} = 3.3$ V) • Low power dissipation : $I_{CC} = 4\mu$ A (Max.) ($T_{a} = 25$ °C) • Input voltage level : $V_{IL} = 0.8$ V (Max.) ($V_{CC} = 3$ V)

 $V_{IH} = 2.0V \text{ (Min.) } (V_{CC} = 3V)$

Power down protection is provided on all inputs.

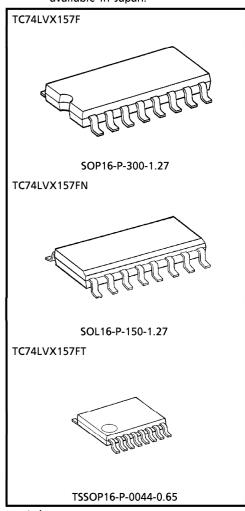
Balanced propagation delays

: t_{pLH}≃t_{pHL}

• Low noise : $V_{OLP} = 0.5V$ (Max.)

Pin and function compatible with 74HC157

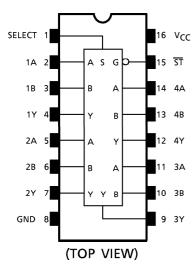
(Note) The JEDEC SOP (FN) is not available in Japan.



Weight

SOP16-P-300-1.27 : 0.18g (Typ.) SOL16-P-150-1.27 : 0.12g (Typ.) TSSOP16-P-0044-0.65 : 0.06g (Typ.)

PIN ASSIGNMENT

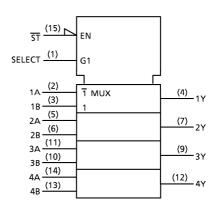


TRUTHTH TABLE

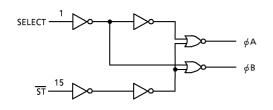
	OUTPUTS			
ST	SELECT	Α	В	OUTPUTS
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	Н	Х	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

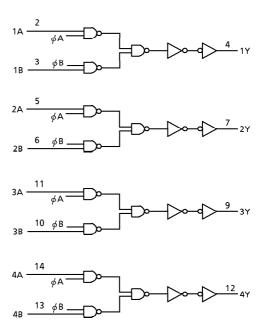
X : Don't Care

IEC LOGIC SYMBOL



SYSTEM DIAGRAM





MAXIMUM RATINGS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage Range	V _{CC}	-0.5~7.0	V
DC Input Voltage	V _{IN}	-0.5~7.0	V
DC Output Voltage	Vout	-0.5~V _{CC} +0.5	V
Input Diode Current	lικ	– 20	mA
Output Diode Current	loк	± 20	mA
DC Output Current	IOUT	± 25	mA
DC V _{CC} /Ground Current	lcc	± 50	mA
Power Dissipation	PD	180	mW
Storage Temperature	T _{stg}	-65∼150	°C

RECOMMENDED OPERATING CONDITIONS

PARAMETER	SYMBOL	RATING	UNIT
Supply Voltage	Vcc	2.0~3.6	V
Input Voltage	V _{IN}	0~5.5	V
Output Voltage	Vout	0~V _{CC}	V
Operating Temperature	T _{opr}	- 40∼85	°C
Input Rise And Fall Time	dt/dv	0~100	ns / V

ELECTRICAL CHARACTERISTICS

DC characteristics

PARAMETER		SYM-			Vcc	Ta = 25°C			Ta = −40~85°C		UNIT
PARA	IVIETER	BOL	1E31 CONDITION		(V)	MIN.	TYP.	MAX.	MIN.	MAX.	UIVIII
					2.0	1.5	_	_	1.5	_	
	"H" Level	V_{IH}			3.0	2.0	_	_	2.0	_	
Input					3.6	2.4	_	_	2.4	_] _v [
Voltage					2.0	_	_	0.5	_	0.5] '
	"L" Level	V_{IL}			3.0	_	_	0.8	_	0.8	
					3.6	_	_	0.8	_	0.8	1
		v _{ОН}	$V_{IN} = V_{IH}$	$I_{OH} = -50\mu A$	2.0	1.9	2.0	_	1.9	_	
	"H" Level			$I_{OH} = -50\mu A$	3.0	2.9	3.0	_	2.9	_	
Output			or V _{IL}	$I_{OH} = -4mA$	3.0	2.58	_	_	2.48	_] _v [
Voltage			V _{IN} = V _{IH}	$I_{OL} = 50 \mu A$	2.0	_	0.0	0.1	_	0.1	1 '
	"L" Level	VOL	OL OL	$I_{OL} = 50 \mu A$	3.0	_	0.0	0.1	_	0.1	
	or VIL		I _{OL} = 4mA	3.0	_	_	0.36	_	0.44		
Input Leakage Current IIN		ΙΝ	V _{IN} = 5.5V or GND		3.6			±0.1	_	± 1.0	μΑ
Quiescent S Current	Supply	lcc	V _{IN} = V _{CC} or GND		3.6	_	_	4.0	_	40.0	μΑ

AC characteristics	(Input $t_r = t_f = 3ns$)
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DADAMETED	SYM-			Ta = 25°C			Ta = -4	UNIT		
PARAMETER	BOL	CONDITION	V _{CC} (V)	C _L (pF)	MIN.	TYP.	MAX.	MIN.	MAX.	OIVIII
	+	+		15		6.6	12.5	1.0	15.5	
Propagation Delay	t _{pLH}		2.7	50		9.1	16.0	1.0	19.0	
Time (A, B-Y)			3.3 ± 0.3	15		5.1	7.9	1.0	9.5	ns
	t _{pHL}		3.3 ± 0.3	50		7.6	11.4	1.0	13.0	
	+		2.7	15		8.9	16.9	1.0	20.5	
Propagation Delay	լ ^ւ pLH	^t pLH	2.7	50		11.4	20.4	1.0	24.0	ns
Time (SELECT-Y)		PHL	3.3 ± 0.3	15		7.0	11.0	1.0	13.0	
	чрнг			50		9.5	14.5	1.0	16.5	
	+	t _{pLH}	2.7	15		9.1	17.6	1.0	20.5	
Propagation Delay	^ւ pLH		2 .,	50		11.6	21.1	1.0	24.0	ns
Time (ST-Y)			3.3 ± 0.3	15		7.2	11.5	1.0	13.5	113
	^t pHL		3.3 ± 0.3	50		9.7	15.0	1.0	17.0	
Output To Output	tosLH	tosi H (Note 1)	2.7	50		_	1.5	_	1.5	nc
1	tosHL	. I (INOLE I)		50		_	1.5	_	1.5	ns
Input Capacitance	CIN	(Note 2)				4	10	_	10	рF
Power Dissipation Capacitance	C _{PD}	(Note 3)				20	_	_	_	рF

(Note 1) Parameter guaranteed by design.

 $(t_{OSLH} = |t_{pLHm} - t_{pLHn}|, t_{OSHL} = |t_{pHLm} - t_{pHLn}|)$

(Note 2) Parameter guaranteed by design.

(Note 3) C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption.

Average operating current can be obtained by the equation :

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/4 \text{ (per bit)}$

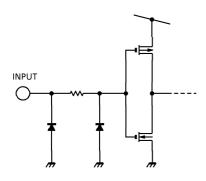
And the total $C_{\mbox{\scriptsize PD}}$ when n pcs. of gate operate can be gained by the following equation :

 C_{PD} (total) = 13 + 7 · n

Noise characteristics (Ta = 25°C, Input $t_r = t_f = 3ns$, $C_L = 50pF$)

PARAMETER	SYMBOL	TEST CONDITION	V _{CC} (V)	TYP.	LIMIT	UNIT
Quiet Output Maximum Dynamic VOL	V _{OLP}		3.3	0.3	0.5	٧
Quiet Output Minimum Dynamic VOL	V _{OLV}		3.3	-0.3	- 0.5	V
Minimum High Level Dynamic Input Voltage	V _{IHD}		3.3		2.0	V
Maximum Low Level Dynamic Input Voltage	V _{ILD}		3.3	1	0.8	V

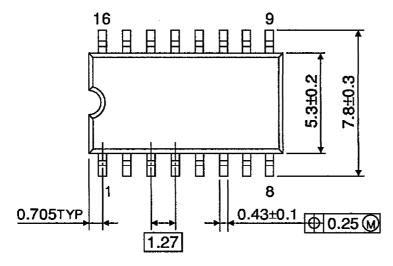
INPUT EQUIVALENT CIRCUIT

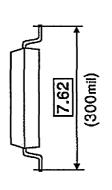


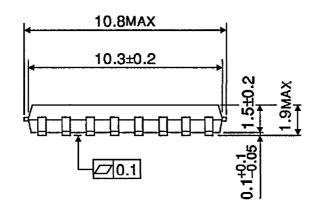
Unit: mm

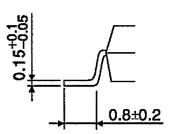
PACKAGE DIMENSIONS

SOP16-P-300-1.27







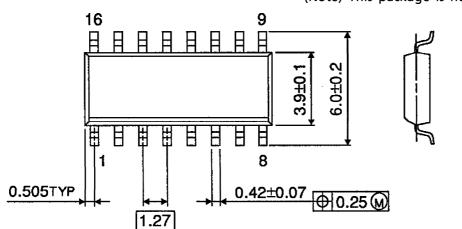


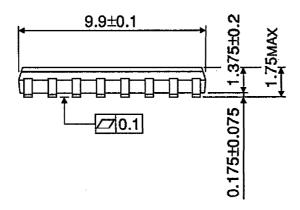
Weight: 0.18g (Typ.)

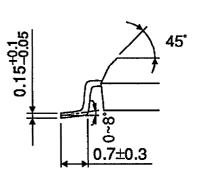
PACKAGE DIMENSIONS

SOL16-P-150-1.27

Unit: mm (Note) This package is not available in Japan.





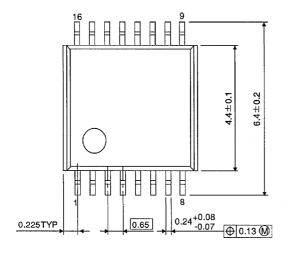


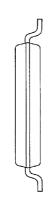
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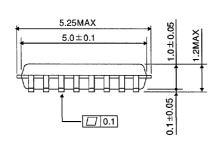
PACKAGE DIMENSIONS

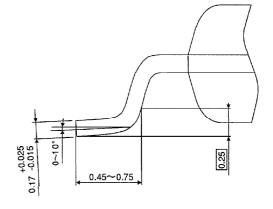
TSSOP16-P-0044-0.65

Unit: mm









Weight: 0.06g (Typ.)

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